SA58632 2 × 2.2 W BTL audio amplifier Rev. 02 – 4 March 2010

**Product data sheet** 

### 1. General description

The SA58632 is a two-channel audio amplifier in an HVQFN20 package. It provides power output of 2.2 W per channel with an 8  $\Omega$  load at 9 V supply. The internal circuit is comprised of two BTL (Bridge-Tied Load) amplifiers with a complementary PNP-NPN output stage and standby/mute logic. The SA58632 is housed in a 20-pin HVQFN package, which has an exposed die attach paddle enabling reduced thermal resistance and increased power dissipation.

### 2. Features

- Low junction-to-ambient thermal resistance using exposed die attach paddle
- Gain can be fixed with external resistors from 6 dB to 30 dB
- Standby mode controlled by CMOS-compatible levels
- Low standby current < 10 μA</p>
- No switch-on/switch-off plops
- High power supply ripple rejection: 50 dB minimum
- ElectroStatic Discharge (ESD) protection
- Output short-circuit to ground protection
- Thermal shutdown protection

### 3. Applications

- Professional and amateur mobile radio
- Portable consumer products: toys and games
- Personal computer remote speakers



### 4. Quick reference data

#### Table 1. Quick reference data

 $V_{CC} = 6 V$ ;  $T_{amb} = 25 \ ^{\circ}C$ ;  $R_L = 8 \Omega$ ;  $V_{MODE} = 0 V$ ; measured in test circuit <u>Figure 3</u>; unless otherwise specified.

opeemea							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage	operating		2.2	9	18	V
lq	quiescent current	$R_L = \infty \ \Omega$	[1]	-	15	22	mA
I <sub>stb</sub>	standby current	$V_{MODE} = V_{CC}$		-	-	10	μA
Po	output power	THD+N = 10 %		1.2	1.5	-	W
		THD+N = 0.5 %		0.9	1.1	-	W
		THD+N = 10 %; V <sub>CC</sub> = 9 V		-	2.2	-	W
THD+N	total harmonic distortion-plus-noise	$P_{0} = 0.5 W$		-	0.15	0.3	%
PSRR	power supply rejection ratio		[2]	50	-	-	dB
			[3]	40	-	-	dB

[1] With a load connected at the outputs the quiescent current will increase, the maximum of this increase being equal to the DC output offset voltage divided by R<sub>L</sub>.

[2] Supply voltage ripple rejection is measured at the output with a source impedance of  $R_s = 0 \Omega$  at the input. The ripple voltage is a sine wave with a frequency of 1 kHz and an amplitude of 100 mV (RMS), which is applied to the positive supply rail.

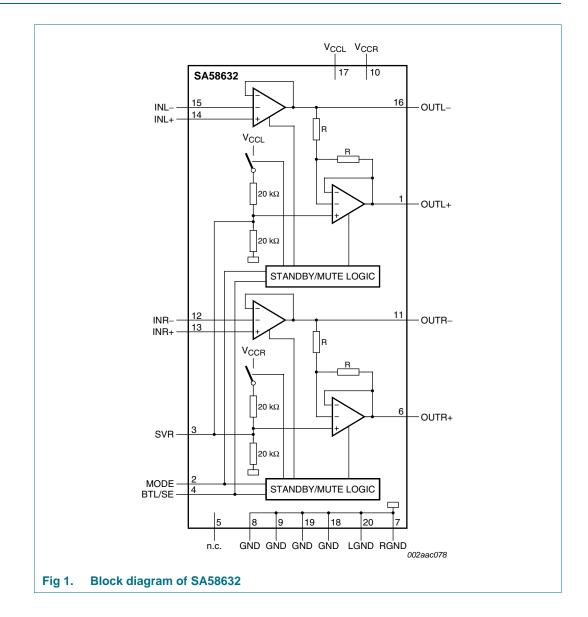
[3] Supply voltage ripple rejection is measured at the output, with a source impedance of  $R_s = 0 \Omega$  at the input. The ripple voltage is a sine wave with a frequency between 100 Hz and 20 kHz and an amplitude of 100 mV (RMS), which is applied to the positive supply rail.

### 5. Ordering information

#### Table 2.Ordering information

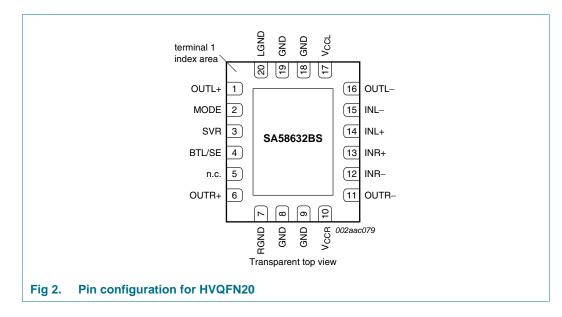
Type number	Package	Package				
	Name	Description	Version			
SA58632BS	HVQFN20	plastic thermal enhanced very thin quad flat package; no leads; 20 terminals; body $6 \times 5 \times 0.85$ mm	SOT910-1			

### 6. Block diagram



## 7. Pinning information

### 7.1 Pinning



### 7.2 Pin description

Symbol	Pin	Description
OUTL+	1	positive loudspeaker terminal, left channel
MODE	2	operating mode select (standby, mute, operating)
SVR	3	half supply voltage, decoupling ripple rejection
BTL/SE	4	BTL loudspeaker or SE headphone operation
n.c.	5	not connected
OUTR+	6	positive loudspeaker terminal, right channel
RGND	7	ground, right channel
GND	8, 9, 18, 19	ground <sup>[1]</sup>
V <sub>CCR</sub>	10	supply voltage; right channel
OUTR-	11	negative loudspeaker terminal, right channel
INR-	12	negative input, right channel
INR+	13	positive input, right channel
INL+	14	positive input, left channel
INL-	15	negative input, left channel
OUTL-	16	negative output terminal, left channel
V <sub>CCL</sub>	17	supply voltage, left channel
LGND	20	ground, left channel

[1] Pins 8, 9, 18 and 19 are connected to the lead frame and also to the substrate. They may be kept floating. When connected to the ground plane, the PCB can be used as heatsink.

SA58632 2

### 8. Functional description

The SA58632 is a two-channel BTL audio amplifier capable of delivering  $2 \times 1.5$  W output power to an 8  $\Omega$  load at THD+N = 10 % using a 6 V power supply. It is also capable of delivering  $2 \times 2.2$  W output power to an 8  $\Omega$  load at THD+N = 10 % using a 9 V power supply. Using the MODE pin, the device can be switched to standby and mute condition. The device is protected by an internal thermal shutdown protection mechanism. The gain can be set within a range of 6 dB to 30 dB by external feedback resistors.

### 8.1 Power amplifier

The power amplifier is a Bridge-Tied Load (BTL) amplifier with a complementary PNP-NPN output stage. The voltage loss on the positive supply line is the saturation voltage of a PNP power transistor, on the negative side the saturation voltage of an NPN power transistor. The total voltage loss is < 1 V. With a supply voltage of 6 V and an 8  $\Omega$  loudspeaker, an output power of 1.5 W can be delivered to the load, and with a 9 V supply voltage and an 8  $\Omega$  loudspeaker an output power of 2.2 W can be delivered.

### 8.2 Mode select pin (MODE)

The device is in Standby mode (with a very low current consumption) if the voltage at the MODE pin is greater than  $V_{CC}$  – 0.5 V, or if this pin is floating. At a MODE voltage in the range between 1.5 V and  $V_{CC}$  – 1.5 V the amplifier is in a mute condition. The mute condition is useful to suppress plop noise at the output, caused by charging of the input capacitor. The device is in Active mode if the MODE pin is grounded or less than 0.5 V (see Figure 6).

### 8.3 BTL/SE output configuration

To invoke the BTL configuration (see Figure 3), the BTL/SE pin is taken to logic HIGH or not connected. The output differentially drives the speakers, so there is no need for coupling capacitors. The headphone can be connected to the amplifier negative outputs using a coupling capacitor for each channel. The headphone common ground is connected to the amplifier ground.

To invoke the Single-Ended (SE) configuration (see Figure 15), the BTL/SE pin is taken to logic LOW or connected to ground. The positive outputs are muted with a DC level of  $0.5V_{CC}$ . Using a coupling capacitor for each channel, speakers can be connected to the amplifier negative outputs. The speaker common ground is connected to the amplifier ground. Headphones can be connected to the negative outputs without using output coupling capacitors. The headphone common ground pin is connected to one of the amplifier positive output pins.

### 9. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage	operating	-0.3	+18	V
VI	input voltage		-0.3	V <sub>CC</sub> + 0.3	V
I <sub>ORM</sub>	repetitive peak output current		-	1	А
T <sub>stg</sub>	storage temperature	non-operating	-55	+150	°C
T <sub>amb</sub>	ambient temperature	operating	-40	+85	°C
V <sub>P(sc)</sub>	short-circuit supply voltage		-	10	V
P <sub>tot</sub>	total power dissipation	HVQFN20	-	2.2	W

### **10. Thermal characteristics**

Table 5.	Thermal characteristics			
Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	80	K/W
		64.5 mm <sup>2</sup> (10 square inch) heat spreader	<u>1</u> 22	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		3	K/W

[1] Thermal resistance is 22 K/W with DAP soldered to 64.5 mm<sup>2</sup> (10 square inch), 1 ounce copper heat spreader.

## 11. Static characteristics

#### Table 6. Static characteristics

 $V_{CC} = 6 \text{ V}; T_{amb} = 25 \text{ °C}; R_L = 8 \Omega; V_{MODE} = 0 \text{ V}; \text{ measured in test circuit Figure 3; unless otherwise specified.}$ 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage	operating		2.2	9	18	V
lq	quiescent current	$R_L = \infty \Omega$	[1]	-	15	22	mA
I <sub>stb</sub>	standby current	$V_{MODE} = V_{CC}$		-	-	10	μΑ
Vo	output voltage		[2]	-	2.2	-	V
$\Delta V_{O(offset)}$	differential output voltage offset			-	-	50	mV
I <sub>IB</sub>	input bias current	pins INL+, INR+		-	-	500	nA
		pins INL-, INR-		-	-	500	nA
V <sub>MODE</sub>	voltage on pin MODE	operating		0	-	0.5	V
		mute		1.5	-	$V_{CC}-1.5$	V
		standby		$V_{CC}-0.5$	-	V <sub>CC</sub>	V
I <sub>MODE</sub>	current on pin MODE	$0 V < V_{MODE} < V_{CC}$		-	-	20	μΑ
V <sub>I(SE)</sub>	input voltage on pin BTL/SE	single-ended (SE)		0	-	0.6	V
V <sub>I(BTL)</sub>	input voltage on pin BTL/SE	BTL		$0.42 \times V_{CC}$	-	V <sub>CC</sub>	V
I <sub>I(SE)</sub>	input current on pin BTL/SE	V <sub>I(SE)</sub> = 0 V; pin connected to ground in SE mode		-	-	100	μΑ

[1] With a load connected at the outputs the quiescent current will increase, the maximum of this increase being equal to the DC output offset voltage divided by R<sub>L</sub>.

SA58632 2

[2] The DC output voltage with respect to ground is approximately  $0.5 \times V_{CC}$ .

### **12. Dynamic characteristics**

#### Table 7. Dynamic characteristics

 $V_{CC} = 6 V$ ;  $T_{amb} = 25 \circ C$ ;  $R_L = 8 \Omega$ ; f = 1 kHz;  $V_{MODE} = 0 V$ ; measured in test circuit <u>Figure 3</u>; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Po	output power	THD+N = 10 %		1.2	1.5	-	W
		THD+N = 0.5 %		0.9	1.1	-	W
		THD+N = 10 %; $V_{CC}$ = 9 V; application demo board		-	2.2	-	W
THD+N	total harmonic distortion-plus-noise	P <sub>o</sub> = 0.5 W		-	0.15	0.3	%
G <sub>v(cl)</sub>	closed-loop voltage gain		<u>[1]</u>	6	-	30	dB
$\Delta Z_i$	differential input impedance			-	100	-	kΩ
V <sub>n(o)</sub>	output noise voltage		[2]	-	-	100	μV
PSRR	power supply rejection ratio		[3]	50	-	-	dB
			[4]	40	-	-	dB
V <sub>O(mute)</sub>	mute output voltage	mute condition	[5]	-	-	200	μV
$\alpha_{cs}$	channel separation			40	-	-	dB

[1] Gain of the amplifier is  $2 \times (R2 / R1)$  in test circuit of Figure 3.

[2] The output noise voltage is measured at the output in a frequency range from 20 Hz to 20 kHz (unweighted), with a source impedance of  $R_s = 0 \Omega$  at the input.

[3] Supply voltage ripple rejection is measured at the output with a source impedance of  $R_s = 0 \Omega$  at the input. The ripple voltage is a sine wave with a frequency of 1 kHz and an amplitude of 100 mV (RMS), which is applied to the positive supply rail.

[4] Supply voltage ripple rejection is measured at the output, with a source impedance of R<sub>s</sub> = 0 Ω at the input. The ripple voltage is a sine wave with a frequency between 100 Hz and 20 kHz and an amplitude of 100 mV (RMS), which is applied to the positive supply rail.

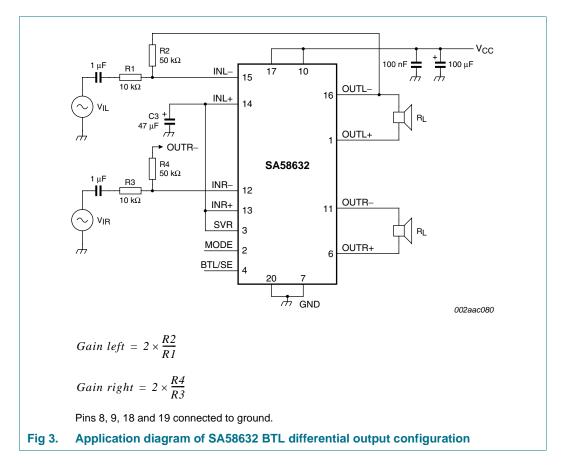
[5] Output voltage in mute position is measured with an input voltage of 1 V (RMS) in a bandwidth of 20 kHz, which includes noise.

SA58632 2

## **13. Application information**

### **13.1 BTL application**

 $T_{amb} = 25 \text{ °C}, V_{CC} = 9 \text{ V}, f = 1 \text{ kHz}, R_L = 8 \Omega, G_v = 20 \text{ dB}, \text{ audio band-pass } 22 \text{ Hz to}$  22 kHz. The BTL diagram is shown in Figure 3.

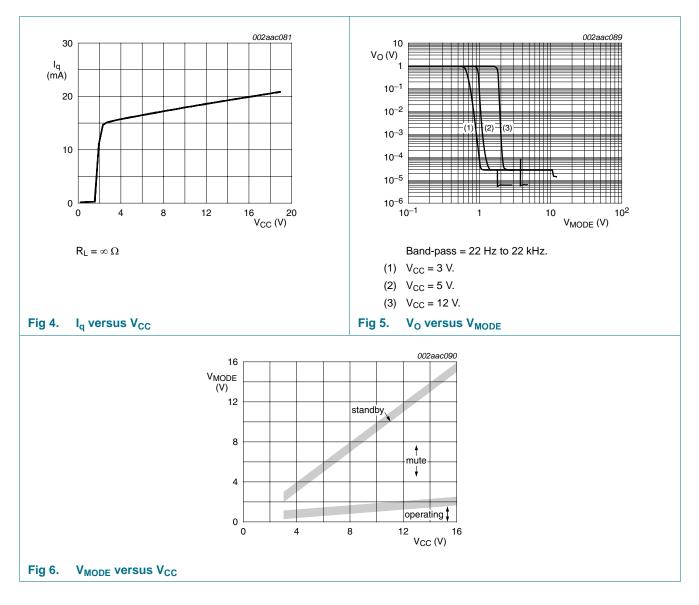


 $2\times2.2$  W BTL audio amplifier

## 14. Test information

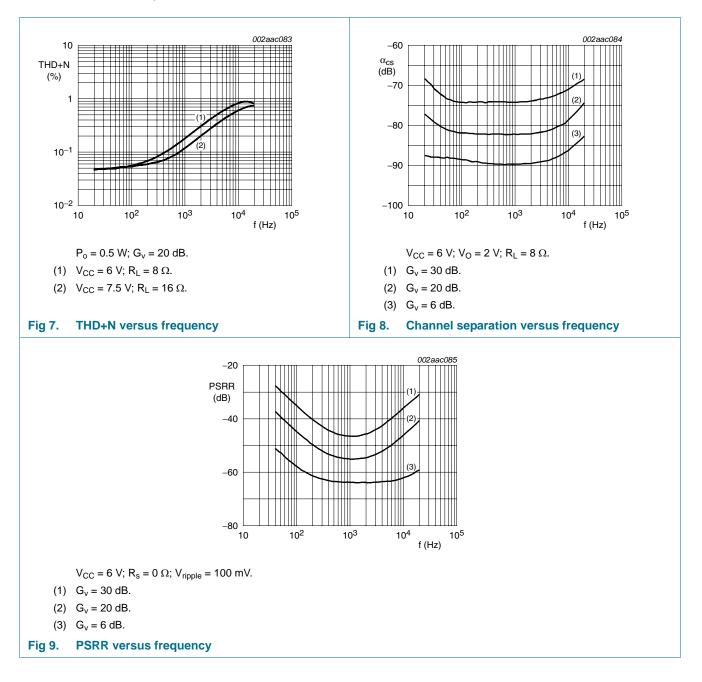
#### 14.1 Static characterization

The quiescent current has been measured without any load impedance (Figure 4). Figure 6 shows three areas: operating, mute and standby. It shows that the DC switching levels of the mute and standby respectively depends on the supply voltage level.



### 14.2 BTL dynamic characterization

The total harmonic distortion-plus-noise (THD+N) as a function of frequency (Figure 7) was measured with a low-pass filter of 80 kHz. The value of capacitor C2 influences the behavior of PSRR at low frequencies; increasing the value of C2 increases the performance of PSRR.



#### **14.3 Thermal behavior**

The measured thermal performance of the HVQFN20 package is highly dependent on the configuration and size of the heat spreader on the application demo board. Data may not be comparable between different semiconductors manufacturers because the application demo boards and test methods are not standardized. Also, the thermal performance of packages for a specific application may be different than presented here, because of the configuration of the copper heat spreader of the application boards may be significantly different.

NXP Semiconductors uses FR-4 type application boards with 1 ounce copper traces with solder coating.

The demo board (see Figure 23) has a 1 ounce copper heat spreader that runs under the IC and provides a mounting pad to solder to the die attach paddle of the HVQFN20 package. The heat spreader is symmetrical and provides a heat spreader on both top and bottom of the PCB. The heat spreader on top and bottom side of the demo board is connected through 2 mm diameter plated through holes. Directly under the DAP (Die Attach Paddle), the top and bottom side of the PCB are connected by four vias. The total top and bottom heat spreader area is 64.5 mm<sup>2</sup> (10 in<sup>2</sup>).

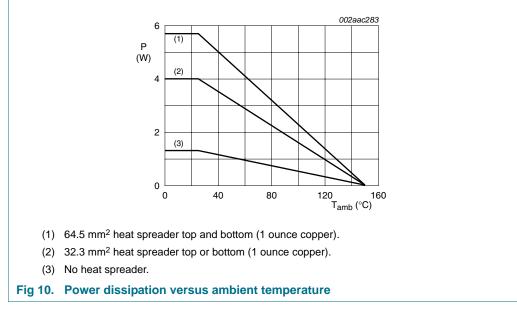
The junction to ambient thermal resistance,  $R_{th(j-a)} = 22 \text{ K/W}$  for the HVQFN20 package when the exposed die attach paddle is soldered to 5 square inch area of 1 ounce copper heat spreader on the demo PCB. The maximum sine wave power dissipation for  $T_{amb} = 25 \text{ °C}$  is given in Equation 1:

$$\frac{150-25}{22} = 5.7 \text{ W} \tag{1}$$

Thus, for  $T_{amb} = 60 \text{ °C}$  the maximum total power dissipation is given in Equation 2:

$$\frac{150-60}{22} = 4.1 \text{ W}$$
(2)

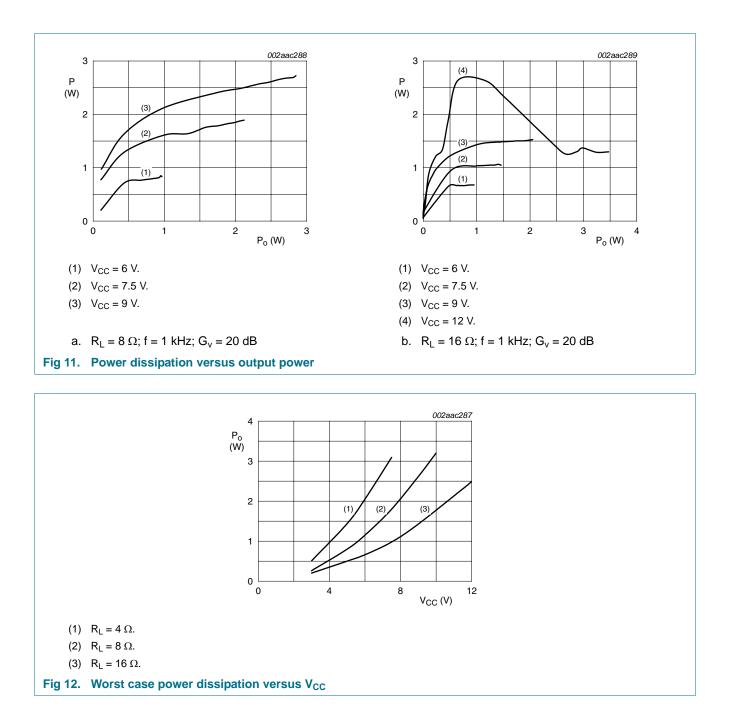
The power dissipation versus ambient temperature curve (Figure 10) shows the power derating profiles with ambient temperature for three sizes of heat spreaders. For a more modest heat spreader using 5 square inch area on the top or bottom side of the PCB, the  $R_{th(j-a)}$  is 31 K/W. When the package is not soldered to a heat spreader, the  $R_{th(j-a)}$  increases to 60 K/W.



The characteristics curves (Figure 11 a and Figure 11 b, Figure 12, Figure 13 a and Figure 13 b, and Figure 14) show the room temperature performance for SA58632 using the demo PCB shown in Figure 23. For example, Figure 11 "Power dissipation versus output power" (a and b) show the performance as a function of load resistance and supply voltage. Worst case power dissipation is shown in Figure 12. Figure 13 a shows that the part delivers typically 2.8 W per channel for THD+N = 10 % using 8  $\Omega$  load at 9 V supply, while Figure 13 b shows that the part delivers 3.3 W per channel at 12 V supply and 16  $\Omega$  load, THD+N = 10 %.

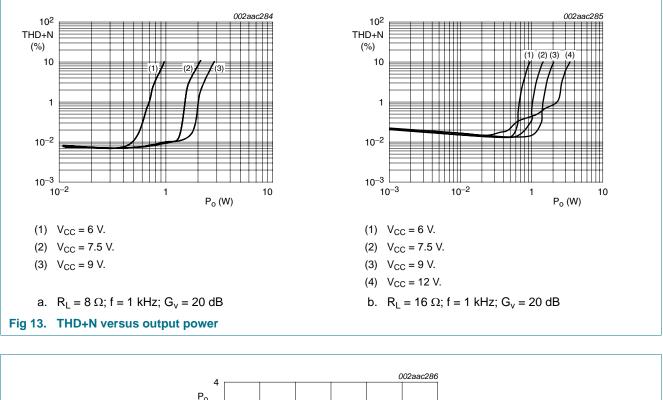
SA58632\_2 Product data sheet

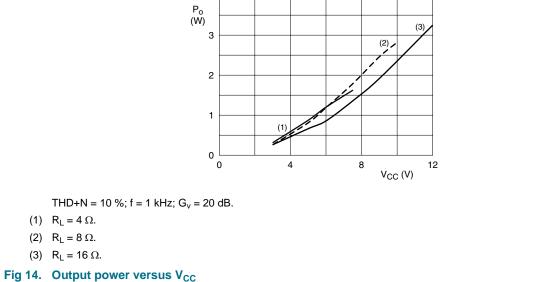
SA58632 2 × 2.2 W BTL audio amplifier



# SA58632

 $\mathbf{2}\times\mathbf{2.2}$  W BTL audio amplifier

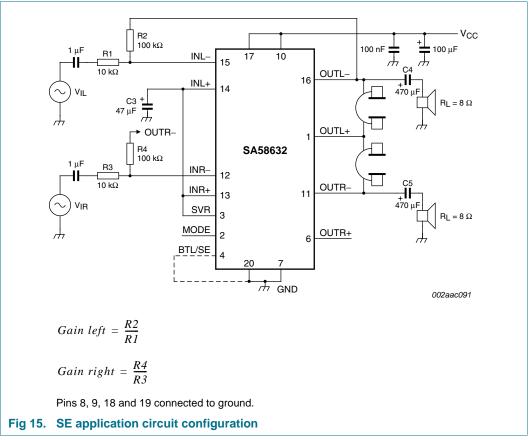




### 14.4 Single-ended application

 $T_{amb}$  = 25 °C;  $V_{CC}$  = 7.5 V; f = 1 kHz;  $R_L$  = 8  $\Omega;$   $G_v$  = 20 dB; audio band-pass 20 Hz to 20 kHz.

The single-ended application diagram is shown in Figure 15.

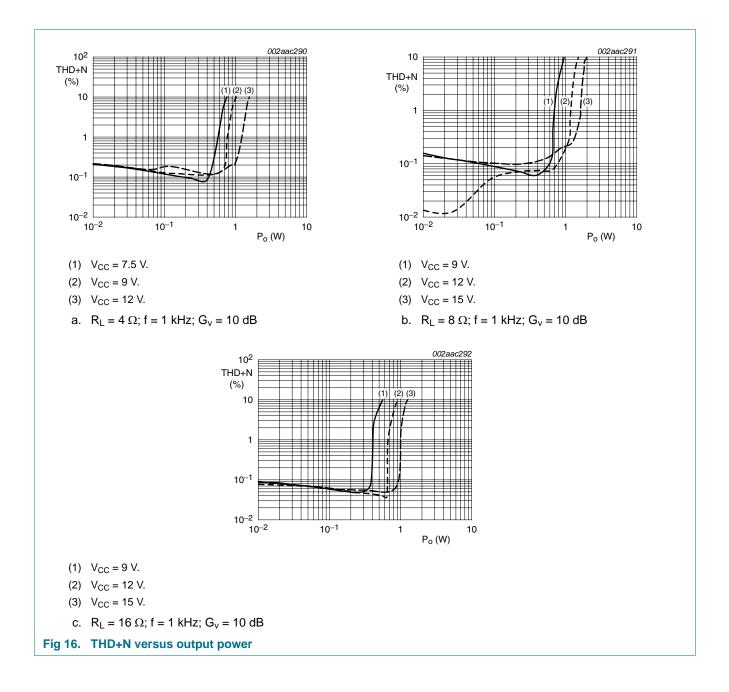


If the BTL/SE pin is to ground, the positive outputs (OUTL+, OUTR+) will be in mute condition with a DC level of  $0.5V_{CC}$ . When a headphone is used (R<sub>L</sub> > 25  $\Omega$ ) the SE headphone application can be used without coupling capacitors by placing the load between negative output and one of the positive outputs (for example, pin 1) as the common pin.

Increasing the value of the tantalum or electrolytic capacitor C3 will result in a better channel separation. Because the positive output is not designed for high output current  $(2 \times I_0)$  at the load impedance (< 16  $\Omega$ ), the SE application with output capacitors connected to ground is advised. The capacitor value of C4/C5 in combination with the load impedance determines the low frequency behavior. The total harmonic distortion-plus-noise as a function of frequency was measured with a low-pass filter of 80 kHz. The value of the capacitor C3 influences the behavior of the PSRR at low frequencies; increasing the value of C3 increases the performance of PSRR.

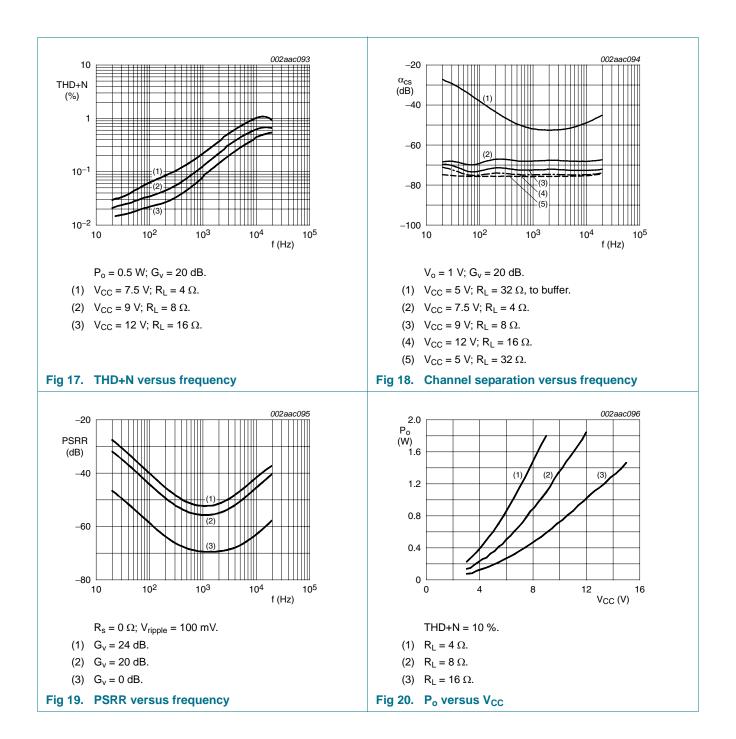
# SA58632

 $\mathbf{2}\times\mathbf{2.2}$  W BTL audio amplifier



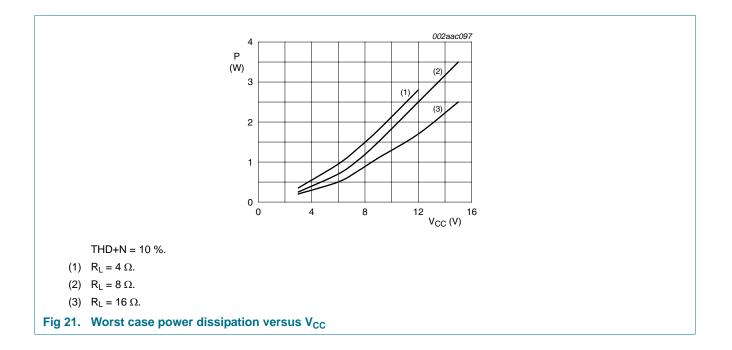
SA58632 2

## SA58632 2 × 2.2 W BTL audio amplifier



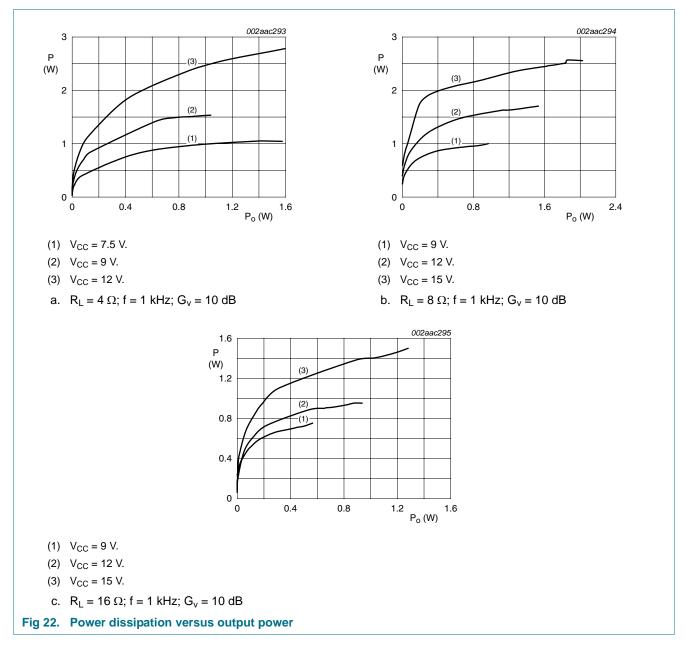
# SA58632

 $\mathbf{2}\times\mathbf{2.2}$  W BTL audio amplifier



# SA58632

 $\mathbf{2}\times\mathbf{2.2}$  W BTL audio amplifier



#### 14.5 General remarks

The frequency characteristics can be adapted by connecting a small capacitor across the feedback resistor. To improve the immunity of HF radiation in radio circuit applications, a small capacitor can be connected in parallel with the feedback resistor (56 k $\Omega$ ); this creates a low-pass filter.

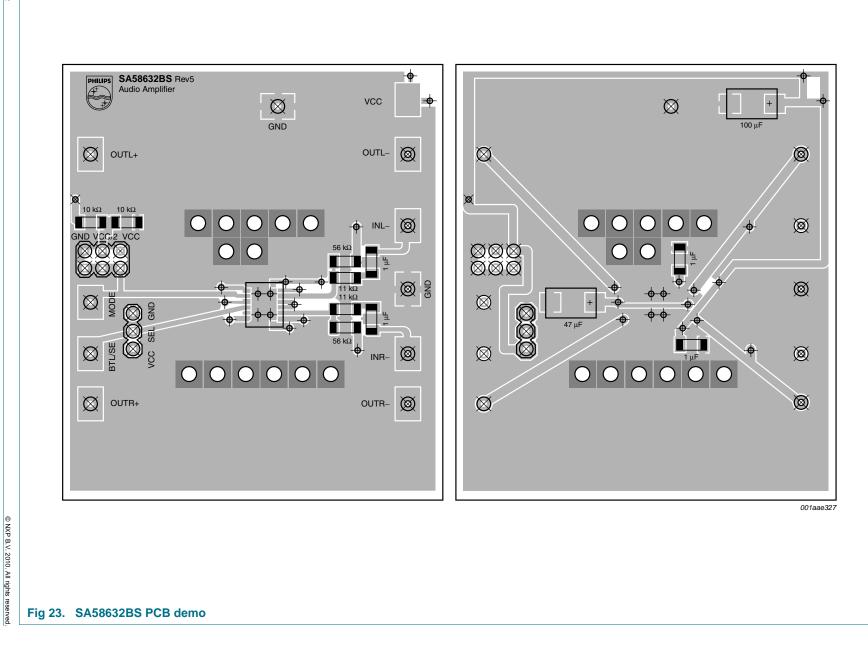
#### 14.6 SA58632BS PCB demo

The application demo board may be used for evaluation in either BTL or SE configuration as shown in the schematics in Figure 3 and Figure 15. The demo PCB is laid out for a  $64.5 \text{ mm}^2$  (10 in<sup>2</sup>) heat spreader (total of top and bottom heat spreader area).

SA58632\_2 Product data sheet

Rev. 02 — 4 March 2010

20 of 28



**NXP Semiconductors** 

2 × 2.2 W BTL audio amplifier

 $\mathbf{2}\times\mathbf{2.2}$  W BTL audio amplifier

## 15. Package outline

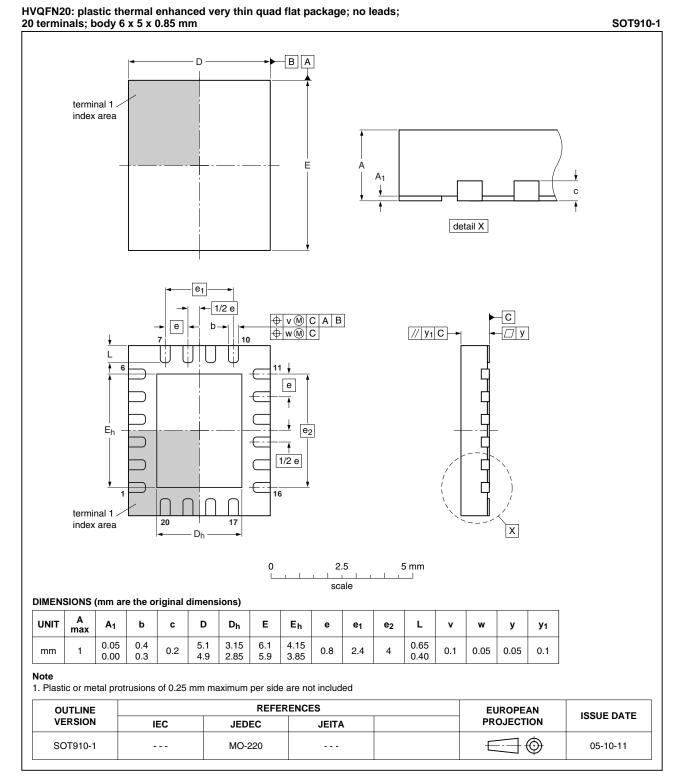


Fig 24. Package outline SOT910-1 (HVQFN20)

### **16. Soldering of SMD packages**

This text provides a very brief insight into a complex technology. A more in-depth account of soldering ICs can be found in Application Note *AN10365 "Surface mount reflow soldering description"*.

### 16.1 Introduction to soldering

Soldering is one of the most common methods through which packages are attached to Printed Circuit Boards (PCBs), to form electrical circuits. The soldered joint provides both the mechanical and the electrical connection. There is no single soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and Surface Mount Devices (SMDs) are mixed on one printed wiring board; however, it is not suitable for fine pitch SMDs. Reflow soldering is ideal for the small pitches and high densities that come with increased miniaturization.

### 16.2 Wave and reflow soldering

Wave soldering is a joining technology in which the joints are made by solder coming from a standing wave of liquid solder. The wave soldering process is suitable for the following:

- Through-hole components
- Leaded or leadless SMDs, which are glued to the surface of the printed circuit board

Not all SMDs can be wave soldered. Packages with solder balls, and some leadless packages which have solder lands underneath the body, cannot be wave soldered. Also, leaded SMDs with leads having a pitch smaller than ~0.6 mm cannot be wave soldered, due to an increased probability of bridging.

The reflow soldering process involves applying solder paste to a board, followed by component placement and exposure to a temperature profile. Leaded packages, packages with solder balls, and leadless packages are all reflow solderable.

Key characteristics in both wave and reflow soldering are:

- Board specifications, including the board finish, solder masks and vias
- · Package footprints, including solder thieves and orientation
- The moisture sensitivity level of the packages
- Package placement
- Inspection and repair
- Lead-free soldering versus SnPb soldering

#### 16.3 Wave soldering

Key characteristics in wave soldering are:

- Process issues, such as application of adhesive and flux, clinching of leads, board transport, the solder wave parameters, and the time during which components are exposed to the wave
- · Solder bath specifications, including temperature and impurities

#### 16.4 Reflow soldering

Key characteristics in reflow soldering are:

- Lead-free versus SnPb soldering; note that a lead-free reflow process usually leads to higher minimum peak temperatures (see <u>Figure 25</u>) than a SnPb process, thus reducing the process window
- Solder paste printing issues including smearing, release, and adjusting the process window for a mix of large and small components on one board
- Reflow temperature profile; this profile includes preheat, reflow (in which the board is heated to the peak temperature) and cooling down. It is imperative that the peak temperature is high enough for the solder to make reliable solder joints (a solder paste characteristic). In addition, the peak temperature must be low enough that the packages and/or boards are not damaged. The peak temperature of the package depends on package thickness and volume and is classified in accordance with Table 8 and 9

#### Table 8. SnPb eutectic process (from J-STD-020C)

Package thickness (mm)	Package reflow temperature (°C)		
	Volume (mm <sup>3</sup> )		
	< 350	≥ 350	
< 2.5	235	220	
≥ 2.5	220	220	

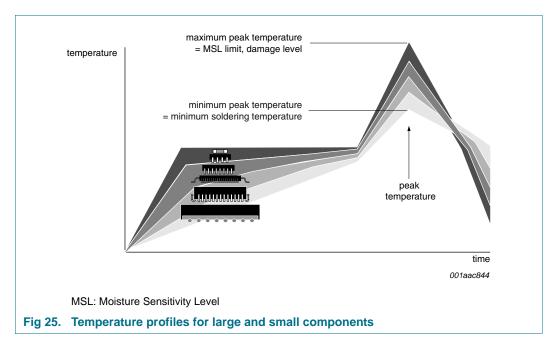
#### Table 9. Lead-free process (from J-STD-020C)

Package thickness (mm)	Package reflow temperature (°C)				
	Volume (mm <sup>3</sup> )				
	< 350	350 to 2000	> 2000		
< 1.6	260	260	260		
1.6 to 2.5	260	250	245		
> 2.5	250	245	245		

Moisture sensitivity precautions, as indicated on the packing, must be respected at all times.

Studies have shown that small packages reach higher temperatures during reflow soldering, see Figure 25.

**SA58632** 



For further information on temperature profiles, refer to Application Note *AN10365 "Surface mount reflow soldering description"*.

## **17. Abbreviations**

Table 10.	Abbreviations
Acronym	Description
BTL	Bridge-Tied Load
CMOS	Complementary Metal Oxide Semiconductor
DAP	Die Attach Paddle
ESD	ElectroStatic Discharge
NPN	Negative-Positive-Negative
PCB	Printed-Circuit Board
PNP	Positive-Negative-Positive
RMS	Root Mean Squared
SE	Single-Ended
THD	Total Harmonic Distortion

# **18. Revision history**

Table 11. Revis	ion history					
Document ID	Release date	Data sheet status	Change notice	Supersedes		
SA58632_2	20100304	Product data sheet	-	SA58632_1		
Modifications:		<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> </ul>				
	<ul> <li>Legal texts</li> </ul>	have been adapted to the new	v company name where a	appropriate.		
	<ul> <li>Table 6 "St</li> </ul>	atic characteristics": Min. value	e for $V_{I(BTL)}$ changed from	"2 V" to "0.42 $\times$ V <sub>CC</sub> ".		
SA58632_1	20060627	Product data sheet	-	-		

### **19. Legal information**

### **19.1 Data sheet status**

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

#### **19.2 Definitions**

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SA58632 2

# SA58632

#### $\mathbf{2}\times\mathbf{2.2}$ W BTL audio amplifier

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# SA58632

 $\mathbf{2}\times\mathbf{2.2}$  W BTL audio amplifier

### 21. Contents

1	General description	. 1
2	Features	. 1
3	Applications	. 1
4	Quick reference data	. 2
5	Ordering information	. 2
6	Block diagram	
7	Pinning information	
7.1	Pinning	
7.2	Pin description	
8	Functional description	5
8.1	Power amplifier	
8.2	Mode select pin (MODE)	
8.3	BTL/SE output configuration	5
9	Limiting values	6
10	Thermal characteristics	6
11	Static characteristics	6
12	Dynamic characteristics	7
13	Application information.	8
13.1	BTL application	
14	Test information	9
14.1	Static characterization.	
14.2	BTL dynamic characterization	10
14.3	Thermal behavior	11
14.4	Single-ended application	15
14.5	General remarks	19
14.6	SA58632BS PCB demo	19
15	Package outline	21
16	Soldering of SMD packages	22
16.1	Introduction to soldering	22
16.2	Wave and reflow soldering	22
16.3	Wave soldering	22
16.4	Reflow soldering	23
17	Abbreviations	24
18	Revision history	25
19	Legal information	26
19.1	Data sheet status	26
19.2	Definitions	26
19.3	Disclaimers	26
19.4		27
20	Contact information	27
21	Contents	28

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